anasonic

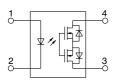




Normally closed type with reinforced insulation

Photo MOS® GE 1 Form B (AQY41OEH)

mm inch



(Height includes standoff)

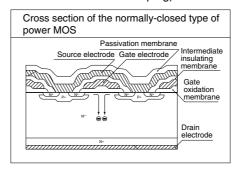
RoHS compliant

FEATURES

1.1 Form B output type

2. Low on-resistance

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Doublediffused and Selective Doping) method.



3. Reinforced insulation of 5,000 V More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

4. Controls low-level analog signals

PhotoMOS feature extremely low closedcircuit offset voltage to enable control of low-level analog signals without distortion.

5. High sensitivity and low onresistance

Can control max. 0.55 A load current with 5 mA input current.

Low on-resistance of Typ.1 Ω (AQY412EH).

6. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Modem
- Telephone equipment
- Electricity, plant equipment
- Sensing equipment

TYPES

Туре	I/O isolation voltage	Output rating*		Package ·	Part No.				Packing quantity	
					Through hole terminal Surface-mount terminal					
		Load Load voltage current	land land	гаскауе			Tape and reel packing style		Tube	Tape and reel
				Tube packing style		Picked from the 1/2-pin side	Picked from the 3/4-pin side			
AC/DC dual use	Reinforced 5,000 Vrms	60 V	550 mA		AQY412EH	AQY412EHA	AQY412EHAX	AQY412EHAZ	1 tube contains:	
		350 V 130 mA DIP4-pin	AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	100 pcs. 1 batch contains:	1,000 pcs.		
		400 V	120 mA		AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ	1,000 pcs.	

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device. (Ex. the label for product number AQY412EHAX is 412EH.)

RATING

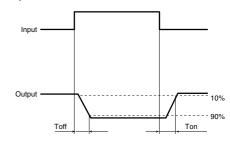
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Remarks
Input	LED forward current	lF		50 mA		
	LED reverse voltage	VR		5 V		
	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
	Load voltage (peak AC)	VL	60 V	350 V	400 V	
Output	Continuous load current	l _L	0.55 A	0.13 A	0.12 A	Peak AC, DC
Output	Peak load current	Ipeak	1.5 A	0.4 A	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	Pout		500 mW		
Total pov	Total power dissipation			550 mW		
I/O isolation voltage		Viso		5,000 Vrms		
Ambient	Operating	Topr	-	40 to +85°C -40 to +185	(Non-icing at low temperatures)	
temperat	ture Storage	T _{stg}	-40 to +100°C −40 to +212°F			

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Condition
	LED operate (OFF) current	Typical	Foff		- I∟=Max.		
Input	LED operate (Or 1) current	Maximum	Ігоп		IL-IVIAX.		
	LED reverse (ON) current	Minimum	l _{Fon}		l∟=Max.		
	LLD reverse (ON) current	Typical	IFon		IL-IVIAX.		
	LED dropout	Typical	VF	1.	Is = 50 mA		
	voltage	Maximum	VF		IL = Max. Within 1 s IF = 5 mA		
	On registance	Typical	Ron	1Ω	18Ω	26Ω	IF = 0 mA IL = Max. Within 1 s
Output	On resistance	Maximum		2.5Ω	25Ω	35Ω	
	Off state leakage current	Maximum	ILeak	10μΑ			I _F = 5 mA V _L = Max.
	Operate (OFF) time*	Typical	Toff	3.0 ms	1.0 ms	0.8 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = \text{Max}.$
	Operate (OFF) time	Maximum	loff	10.0 ms	3.0	ms	
- ,	Reverse (ON) time*	Typical	Ton	0.2 ms	0.3 ms	0.2 ms	I _F = 5 mA → 0 mA
Transfer characteristics	neverse (ON) time	Maximum	Ion		I∟ = Max.		
	I/O conscitones	Typical		0.8 pF			f =1MHz
	I/O capacitance	Maximum	Ciso		V _B = 0 V		
	Initial I/O isolation resistance	Riso		500 V DC			

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

It	em	Symbol	ymbol Min. Max.		
LED	current	l _F 5 30 1			
AQY412EH(A)	Load voltage (Peak AC)	VL	_	48	V
AQ1412EN(A)	Continuous load current	lı.	_	0.55	Α
AQY410EH(A)	Load voltage (Peak AC)	VL	_	280	V
AQT4TUEN(A)	Continuous load current	lı.	_	0.13	Α
AQY414EH(A)	Load voltage (Peak AC)	VL	_	320	٧
AQ1414EN(A)	Continuous load current	l _L	_	0.12	Α

■ These products are not designed for automotive use.

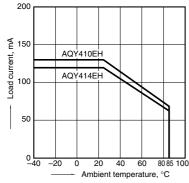
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

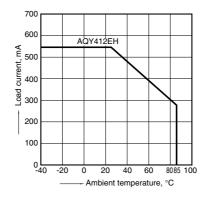
Allowable ambient temperature: –40 to +85 $^{\circ}$ C

-40 to +185°F



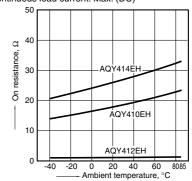
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to $+85^{\circ}$ C -40 to $+185^{\circ}$ F



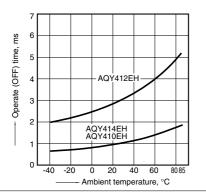
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 0 mA; Load voltage: Max.(DC); Continuous load current: Max. (DC)



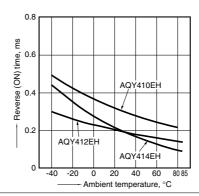
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



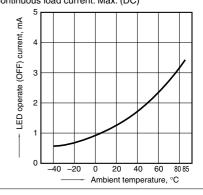
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



5. LED operate (OFF) current vs. ambient temperature characteristics

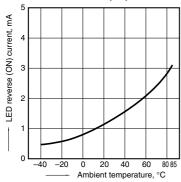
Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



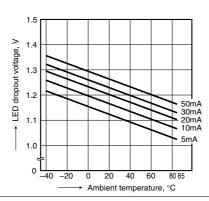
6. LED reverse (ON) current vs. ambient temperature characteristics Sample: All types;

Load voltage: Max. (DC);

Continuous load current: Max. (DC)



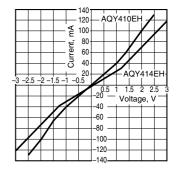
7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



8-(1). Current vs. voltage characteristics of output at MOS portion

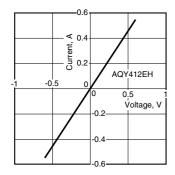
Measured portion: between terminals 3 and 4;

Ambient temperature: 25°C 77°F



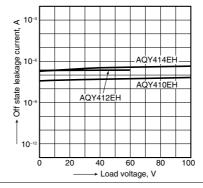
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



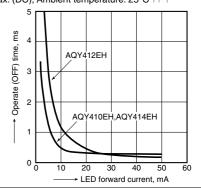
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



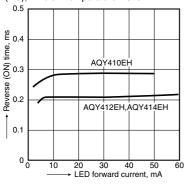
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77'



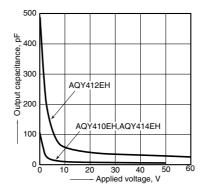
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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